APPLICATION# 10/725,593

EAST Search History

				·		
L4	0	((a display adj device) with (level	US-PGPUB;	OR	ON	2006/05/27 23:22
		adj converting adj circuit) with (tft	USPAT;			
		or thin adj film adj transistor\$1)	USOCR;			
		with (substrate\$1) and (level adj	EPO; JPO;			
		converting adj circuit) with	DERWENT;			
		(non\$1differential adj input adj	IBM_TDB			
		signal\$1) same (amplitude "1.2V				
		or less") with (large adj amplitude				
		adj signal\$1) and (input adj				
		signal\$1) with (control\$3 adj				
		signal\$1) with (first adj conductive				
		adj type) adj (first adj transistor)				
		with connect\$3 with (first adj				
		power adj source adj line) same				
		(first adj voltage) with (output adj				
		terminal) and (gate adj electrode)				
		with (input adj signal\$1) with (first				
		adj capacitive adj element) and				
		(second adj conductive adj type)				
		with (second adj transistor) with				
		(connect\$3) with (output adj				
		terminal) with (second adj power				
		adj source adj line\$1) same				
		(second adj voltage) and (gate adj				
		electrode) with (input adj				
		signal\$1) with (second adj				
		capacitive adj element) and (first				
		adj bias adj circuit) with (first adj				
		bias adj voltage) same (gate adj				
		electrode) with (first adj				
		transistor) and (second adj bias				
	,	adj circuit) with (second adj bias				
		adj voltage) same (gate adj				
		electrode) with (second adj				
		transistor) and (first adj bias adj				
		voltage) same (voltage adj turn\$1				
		adj off) and (first adj transistor)				
		same (voltage) with (gate adj				
		electrode) same (first adj				
		transistor) with (maximum adj				
		value\$1) and (second adj bias adj				
		voltage) with (voltage adj turn\$1				
		off) same (second adj transistor)				
-		same (voltage) with (gate adj				
		electrode\$1) with (second adj				
		transistor) with (minimum adj				
		value) and (first adj switch\$3)				
		with (first adj electrode) with				
		connect\$3 with (first adj power				
		adj source adj line\$1) with (first				
		adj voltage\$1) and (second adj				
		switch\$3 adj element) with				
		(second adj electrode\$1) with				
F/27/06	11.24.44.55	connect\$3 with (second adj				
D/27/06	11:31:44 PM	electrode\$1) with (first adj				Page 3
		switch\$3 adj element) and (first				
I	I	adj electrode) with connect\$3 with		i	l	1

((a display adj device) with (level adj converting adj circuit) with (tft or thin adj film adj transistor\$1) with (substrate\$1) and (level adj converting adj circuit) with (non\$1differential adj input adj signal\$1) same (amplitude "1.2V or less") with (large adj amplitude adj signal\$1) and (input adj signal\$1) with (control\$3 adj signal\$1) with (first adj conductive adj type) adj (first adj transistor) with connect\$3 with (first adj power adj source adj line) same (first adj voltage) with (output adj terminal) and (gate adj electrode) with (input adj signal\$1) with (first adj capacitive adj element) and (second adj conductive adj type) with (second adj transistor) with (connect\$3) with (output adj terminal) with (second adj power adj source adj line\$1) same (second adj voltage) and (gate adj electrode) with (input adj signal\$1) with (second adj capacitive adj element) and (first adj bias adj circuit) with (first adj bias adj voltage) same (gate adj electrode) with (first adj transistor) and (second adj bias adj circuit) with (second adj bias adj voltage) same (gate adj electrode) with (second adj transistor) and (first adj bias adj voltage) same (voltage adj turn\$1 adj off) and (first adj transistor) same (voltage) with (gate adj electrode) same (first adj transistor) with (maximum adj value\$1) and (second adj bias adj voltage) with (voltage adj turn\$1 off) same (second adj transistor) same (voltage) with (gate adj electrode\$1) with (second adj transistor) with (minimum adj value) and (first adj switch\$3) with (first adj electrode) with connect\$3 with (first adj power adj source adj line\$1) with (first adj voltage\$1) and (second adj switch\$3 adj element) with (second adj electrode\$1) with connect\$3 with (second adj electrode\$1) with (first adj switch\$3 adj element) and (first adj electrode) with connect\$3 with (second adj electrode) with tranistor and (third adj transistor) with (gate adj electrode) same (output adj voltage) with (sample adj holding adj circuit) and (second adj switch\$3 adj element) with (second adj electrode\$1) with connect\$3 with (second adj electrode\$1) with (first adj switch\$3 adj element) and (first adj electrode) with connect\$3 with (second adj electrode) with (third adj transistor) and (inverter adj circuit) with (first adj power adj source adj line\$1) with (second adj power adj source adj line\$1) and (output adj voltage) with (voltage adj holding adj circuit) with (input\$4) with (inverter adj circuit) and (third adj bias adj circuit)).clm.